
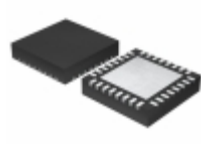
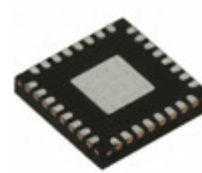

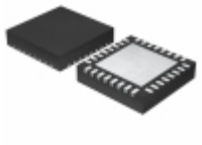
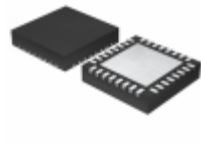
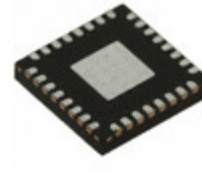
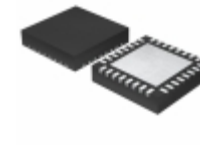


	<h2 style="color: red;">SI4752DY-T1-GE3</h2>
 <p>Not Actual Photo YIC International Co., Limited.</p>	<p>codice articolo del costruttore: SI4752DY-T1-GE3</p> <hr/> <p>Costruttore / Marca: Electro-Films (EFI) / Vishay</p> <hr/> <p>Parte della descrizione: MOSFET N-CH 30V 25A 8-SO</p> <hr/> <p>Specifiche:  SI4752DY-T1-GE3.pdf</p> <hr/> <p>Stato di RoHS: Senza piombo / RoHS conforme</p> <hr/> <p>Condizione di scorta: New original, 3356 pcs Stock Available.</p> <hr/> <p>Nave da: Hong Kong</p> <hr/> <p>Modo di spedizione: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

specificazioni

Modello di prodotti	SI4752DY-T1-GE3
fabbricante	Electro-Films (EFI) / Vishay
Descrizione	MOSFET N-CH 30V 25A 8-SO
Categoria	Prodotti a semiconduttore discreti > Transistor-FET,
Stato parte	3356 pcs Stock
Vgs (th) (max) a Id	2.2V @ 1mA
Vgs (Max)	±20V
Tecnologia	MOSFET (Metal Oxide)
Contenitore dispositivo fornitore	8-SO
Serie	SkyFET®, TrenchFET®
Rds On (max) a Id, Vgs	5.5 mOhm @ 10A, 10V
Dissipazione di potenza (max)	3W (Ta), 6.25W (Tc)
imballaggio	Tape & Reel (TR)
Contenitore / involucri	8-SOIC (0.154", 3.90mm Width)
temperatura di esercizio	-55°C ~ 150°C (TJ)
Tipo montaggio	Surface Mount
Moisture Sensitivity Level (MSL)	1 (Unlimited)
Stato senza piombo / Stato RoHS	Lead free / RoHS Compliant
Capacità di ingresso (Ciss) (Max) @ Vds	1700pF @ 15V
Carica Gate (Qg) (Max) @ Vgs	43nC @ 10V
Tipo FET	N-Channel
Caratteristica FET	Schottky Diode (Body)
Tensione dell'azionamento (Max Rds On, Min Rds On)	4.5V, 10V
Tensione drain-source (Vdss)	30V
Descrizione dettagliata	N-Channel 30V 25A (Tc) 3W (Ta), 6.25W (Tc) Surface
Corrente - Drain continuo (Id) @ 25 ° C	25A (Tc)

Potresti essere anche interessato:

 <p>SI4752DY-T1-GE3 Vishay Siliconix MOSFET N-CH 30V 25A 8-SO</p>	 <p>SI4753-A10-AM Silicon Labs IC CAR RAD RX AM/FM/LW/SW 32QFN</p>	 <p>SI4752-A40-AMR Silicon Labs IC CAR RAD RX AM/FM/LW/SW 32QFN</p>	 <p>SI4752DY-T1-E3 VISHAY SI4752DY-T1-E3 VISHAY</p>
 <p>SI4753-A10-GMR Silicon Labs IC CAR RAD RX AM/FM/LW/SW 32QFN</p>	 <p>SI4753-A10-AMR Silicon Labs IC CAR RAD RX AM/FM/LW/SW 32QFN</p>	 <p>SI4752-A40-GM Silicon Labs IC CAR RAD RX AM/FM/LW/SW 32QFN</p>	 <p>SI4753-A10-GM Silicon Labs IC CAR RAD RX AM/FM/LW/SW 32QFN</p>

SI4752DY-T1-GE3 Parola chiave correlata

Di Più

SI4752DY-T1-GE3 Electro-Films (EFI) / Vishay	Scheda tecnica SI4752DY-T1-GE3	Schede tecniche SI4752DY-T1-GE3	SI4752DY-T1-GE3 PDF	Electro-Films (EFI) / Vishay SI4752DY-T1-GE3
SI4752DY-T1-GE3 elettronico	Componenti SI4752DY-T1-GE3	Distributore SI4752DY-T1-GE3	Immagine SI4752DY-T1-GE3	SI4752DY-T1-GE3 Part
SI4752DY-T1-GE3 Prezzo	SI4752DY-T1-GE3 Produttore	Immagine SI4752DY-T1-GE3	Stock SI4752DY-T1-GE3	Inventario SI4752DY-T1-GE3
SI4752DY-T1-GE3 Nuovo	SI4752DY-T1-GE3 Originale	SI4752DY-T1-GE3 garantito	SI4752DY-T1-GE3 RFQ	SI4752DY-T1-GE3 Ordina online

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